

	Type	L #	Hits	Search Text	DBs
1	BRS	L1	3468	327/108	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
2	BRS	L2	597919	diode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
3	BRS	L3	1341	1 and 2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
4	BRS	L4	477674 1	well	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
5	BRS	L5	886	3 and 4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
6	BRS	L6	1732	327/112	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
7	BRS	L7	593	6 and 2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
8	BRS	L8	414	7 and 4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
9	BRS	L9	151	8 not 3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB

	Type	L #	Hits	Search Text	DBs
10	BRS	L10	617	327/389	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
11	BRS	L11	184	10 and 2 and 4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
12	BRS	L12	601	327/391	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
13	BRS	L13	151	12 and 2 and 4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
14	BRS	L14	69	13 not 11	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
15	BRS	L15	1272	327/427	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
16	BRS	L16	264109	15 annd 2 and 4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
17	BRS	L17	468	15 and 2 and 4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
18	BRS	L18	265	17 not 5 not 9 not 13	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB

	Type	L #	Hits	Search Text	DBs
19	BRS	L19	184	327/430 or 327/431	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
20	BRS	L20	69	19 and 2 and 4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
21	BRS	L21	880	327/434	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
22	BRS	L22	330	21 and 2 and 4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
23	BRS	L23	70	22 not 3 not 9 not 11 not 13 not 18	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
24	BRS	L24	393	327/435 or 327/436	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
25	BRS	L25	134	24 and 2 and 4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
26	BRS	L26	755	327/437	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
27	BRS	L27	189	26 and 2 and 4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB

	Type	L #	Hits	Search Text	DBs
28	BRS	L28	107	27 not 18 not 20 not 23 not 25	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
29	BRS	L29	435	327/215	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
30	BRS	L30	37	29 and 2 and 4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
31	BRS	L31	200	327/217	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
32	BRS	L32	22	31 and 2 and 4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
33	BRS	L33	249	327/219	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
34	BRS	L34	20	33 and 2 and 4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
35	BRS	L35	24	327/220	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
36	BRS	L36	1	(switch\$3 same (second adj (PFET or p-channel or npn)) same well same diode same (nFET or npn or n- channel)).clm.	US-PGPUB

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37	BRS	L37	1	((second adj (PFET or p-channel or pnp)) same well same diode same (nFET or npn or n-channel) same (pull adj up) same capacitor).clm.	US-PGPUB
38	BRS	L38	10	((third adj (PFET or p-channel or pnp)) same diode same (nFET or npn or n-channel)).clm.	US-PGPUB
39	BRS	L39	1	((third adj (PFET or p-channel or pnp)) same diode same (nFET or npn or n-channel) same intermediate same voltage).clm.	US-PGPUB
40	BRS	L40	0	((set adj reset adj latch) or (RS adj latch)) adj (second adj (pFET or pnp or p-channel)) same diode same (nFET or n-channel or npn)).clm.	US-PGPUB
41	BRS	L41	0	((second adj (nFET or n-channel or npn)) same (gate same (voltage or VDD or VCC)) same (fourth adj (pFET or p-channel or pnp)) same (second adj diode\$1)).clm.	US-PGPUB
42	BRS	L42	3191	326/83 or 326/84 or 326/85	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
43	BRS	L43	640	42 and 2 and 4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
44	BRS	L44	402	43 not 3 not 7	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB